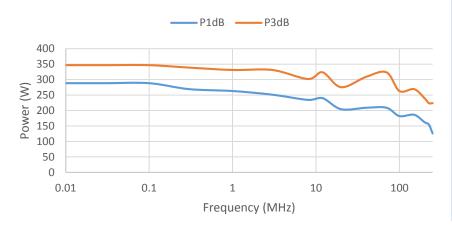


VBA250-200

0.01-250MHz 200W Amplifier



0.01-250MHz 200W P1dB



- Rugged push-pull MOSFET technology
- Class A for maximum mismatch drive

The VBA250-200 is a member of our family of 10kHz-250MHz high power amplifiers, designed primarily for EMC applications.

It is based on rugged push-pull MOSFET technology, for extra even order harmonic suppression.

The amplifier operates in class A, the benefits for EMC applications being very low distortion and tolerance of 100% mismatch. Fold-back protection is neither fitted nor needed! This makes it supremely suited for very demanding transducer requirements



Technical Specification

Electrical

Frequency Range 10kHz-250MHz

(Instantaneous)

Rated Output Power 250W Min (10kHz-80MHz),200W Min(80-250MHz)
Output Power at 1dB 200WMin (10kHz-80MHz),150W Min (80-225MHz)

Gain Compression

Gain 54dB
Third Order Intercept 64dBm

Point (see note 1)

Gain variation with ±2dB

Frequency

Harmonics at 150W Better than -20dBc

Output Power

Output Impedance 50 Ohms
Stability Unconditional
Output VSWR Tolerance Infinity:1

(see note 2)

Input VSWR 2:1 (Max)

Supply Voltage 100 - 240V ac (+/- 10%)

Supply Frequency Range 45-63Hz
Supply Power <1kVA (Max)
Mains Connector IEC 320

Mechanical

RF Connector Style Type N Female

Safety Interlock Dual input, S/C and/or O/C to Mute

USB/GPIB Interface Optional

Dimensions 19 inch, 4U Case, 500mm deep

Mass 18kg Operating Temperature 0-40°C

Range

Case Style Options Rack mount with Front or Rear panel connectors

Bench mount with Front panel connectors

Regulatory Compliance

Conducted and Radiated EN61326 Class A

Emissions

Conducted and Radiated EN61326:1997 Table 1

Immunity

Safety EN61010-1

Notes

1 The third order intercept point is a nominal value, as its calculation depends upon the power level at which distortion measurements are made.

2 Output VSWR tolerance is specified for excitation within the permitted levels and frequency range.



